



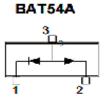


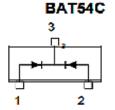
SILICON PLANAR SCHOTTKY DIODES

BAT54A BAT54C BAT54S



SOT-23

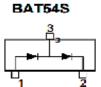




SOT-23 SMD Package RoHS compliant

Marking

BAT54A = L42 BAT54C = L43 BAT54S = L44



APPLICATION: Ultra High Speed Switching Diodes

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	VALUE	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	30	V
Forward Current (DC)	I _F	200	mA
Repetitive Peak Forward Current	I _{FRM}	300	mA
Non Repetitive Peak Forward Current t<1s	I _{FSM}	600	mA
Power Dissipation T _a =25°C	P _D	230	mW
Storage Temperature Range	T _{stg}	-55 to +150	°C
Junction Temperature	T _i	125	°C

Thermal Resistance

Junction to Ambient in free air, Mounted on a Ceramic Substrate of 10mm x 8mm x 0.6mm	R _{th (j-a)}	430	K/W
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ELECTRICAL CHARACTERISTICS at (Ta = 25 °C Unless otherwise specified)

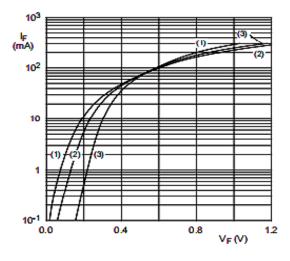
DADAMETED	SYMBOL	TEST CONDITION	VALUE		UNIT	
PARAMETER SYM		. TEST CONDITION		TYP		MAX
Forward Voltage	V _F	I _F =0.1mA			0.24	V
		I _F = 1mA			0.32	V
		I _F = 10mA		-	0.40	٧
		I _F = 30mA		-	0.50	٧
		I _F = 100mA		-	1.00	٧
Reverse Current	I _R	V _R =25V		-	2.0	μΑ
Reverse Breakdown Voltage	$V_{(BR)}$	I _R =100μA	30	-		рF
DYNAMIC CHARACTERISTICS						
Diode Capacitance	Cd	V _R =1V, f=1MHz		I	15	>
Reverse Recovery Time		When Switched from				
	t _{rr}	I _F =10mA to			5	ns
		I _R =10mA, measured				
		at I _{RR} =1mA, R _L =100 Ω				





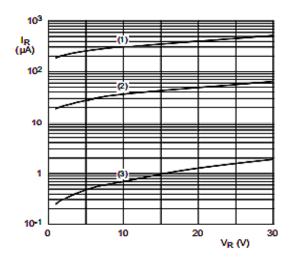
TYPICAL CHARACTERISTIC CURVES

Fig 1: Forward current as a function of forward voltage; typical values



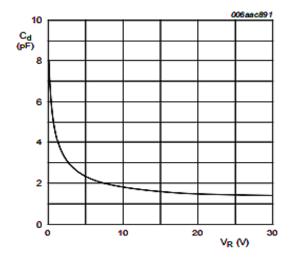
- (1) T_{amb} = 125 °C
- (2) T_{amb} = 85 °C
- (3) T_{amb} = 25 °C

Fig 2: Reverse current as a function of reverse voltage; typical values



- (1) T_{amb} = 125 °C
- (2) T_{amb} = 85 °C
- (3) T_{amb} = 25 °C

Fig 3: Diode capacitance as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

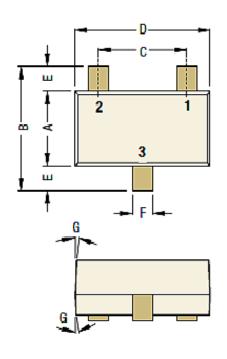


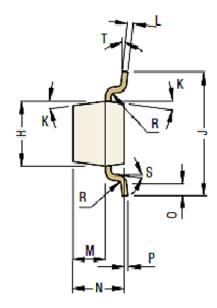




PACKAGE DETAILS

SOT-23 Formed SMD Package





DIM	MIN	MAX	
Α	1.20	1.40	
В	2.10	2.64	
С	1.85	1.95	
D	2.80	3.04	
Е	0.54	0.67	
F	0.30	0.50	
G	3 DEG		
Н		1.30	
J	2.10	2.64	
K	7 DEG		
L	0.08	0.20	
М	0.58	0.62	
N	0.70	1.02	
0	0.21		
Р	0.02	0.15	
R		0.08	
S	2°	8°	
T	2°	10°	
A II aliana a maria ana a maria ana a			

All dimensions are in mm

BAT54A Pin Configuration

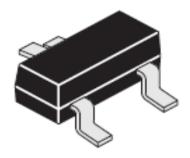
- 1. CATHODE
- 2. CATHODE
- 3. ANODE

BAT54C Pin Configuration

- 1. ANODE
- 2. ANODE
- 3. CATHODE

BAT54C Pin Configuration

- 1. ANODE
- 2. CATHODE
- 3. ANODE / CATHODE



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Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level			
Level	Time	Condition	
1	Unlimited	≤30 °C / 85% RH	
2	1 Year	≤30 °C / 60% RH	
2a	4 Weeks	≤30 °C / 60% RH	
3	168 Hours	≤30 °C / 60% RH	
4	72 Hours	≤30 °C / 60% RH	
5	48 Hours	≤30 °C / 60% RH	
5a	24 Hours	≤30 °C / 60% RH	
6	Time on Label(TOL)	≤30 °C / 60% RH	

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Customer Notes

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



Continental Device India Pvt. Limited

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